NSN 5961-01-103-4877

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Inclosure Material:

Metal

Overall Length:

0.450 inches

Overall Diameter:

1.550 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to emitter voltage/static/base open and 100.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

50.00 amperes source cutoff current and 7.50 amperes source cutoff current

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector absolute

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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